

PS9013

R08DS0136EJ0100

Rev.1.00

Mar 11, 2016

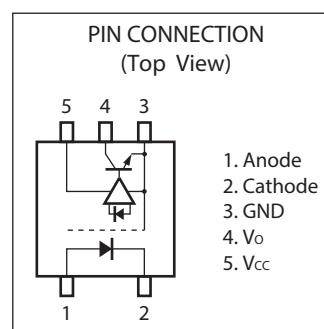
1 Mbps, OPEN COLLECTOR OUTPUT, HIGH CMR, IPM DRIVER, 5-PIN SSOP (LSO5) PHOTOCOUPLER

DESCRIPTION

The PS9013 is an optically coupled isolator containing a GaAlAs LED on the input side and a photo diode and a signal processing circuit on the output side on one chip. The PS9013 is specified high CMR and pulse width distortion with operating temperature. It is suitable for IPM drive.

FEATURES

- Long creepage distance (8 mm MIN.)
- High common mode transient immunity ($CM_H, CM_L = \pm 50 \text{ kV}/\mu\text{s MIN.}$)
- Operating Ambient Temperature (125 °C MAX.)
- High-speed response ($t_{PHL} = 500 \text{ ns MAX.}, t_{PLH} = 750 \text{ ns MAX.}$)
- Maximum propagation delays ($t_{PLH} - t_{PHL} = 270 \text{ ns TYP.}$)
- High isolation voltage ($BV = 5\,000 \text{ V r.m.s.}$)
- Open collector output
- Embossed tape product : PS9013-F3: 3 000 pcs/reel
- Pb-Free product
- Safety standards
 - UL approved: UL1577, Double protection
 - CSA approved: CA5A, CAN/CSA-C22.2 60065, CAN/CSA-C22.2 60950-1, Reinforced insulation)
 - VDE approval: DIN EN 60747-5-5 (Option)

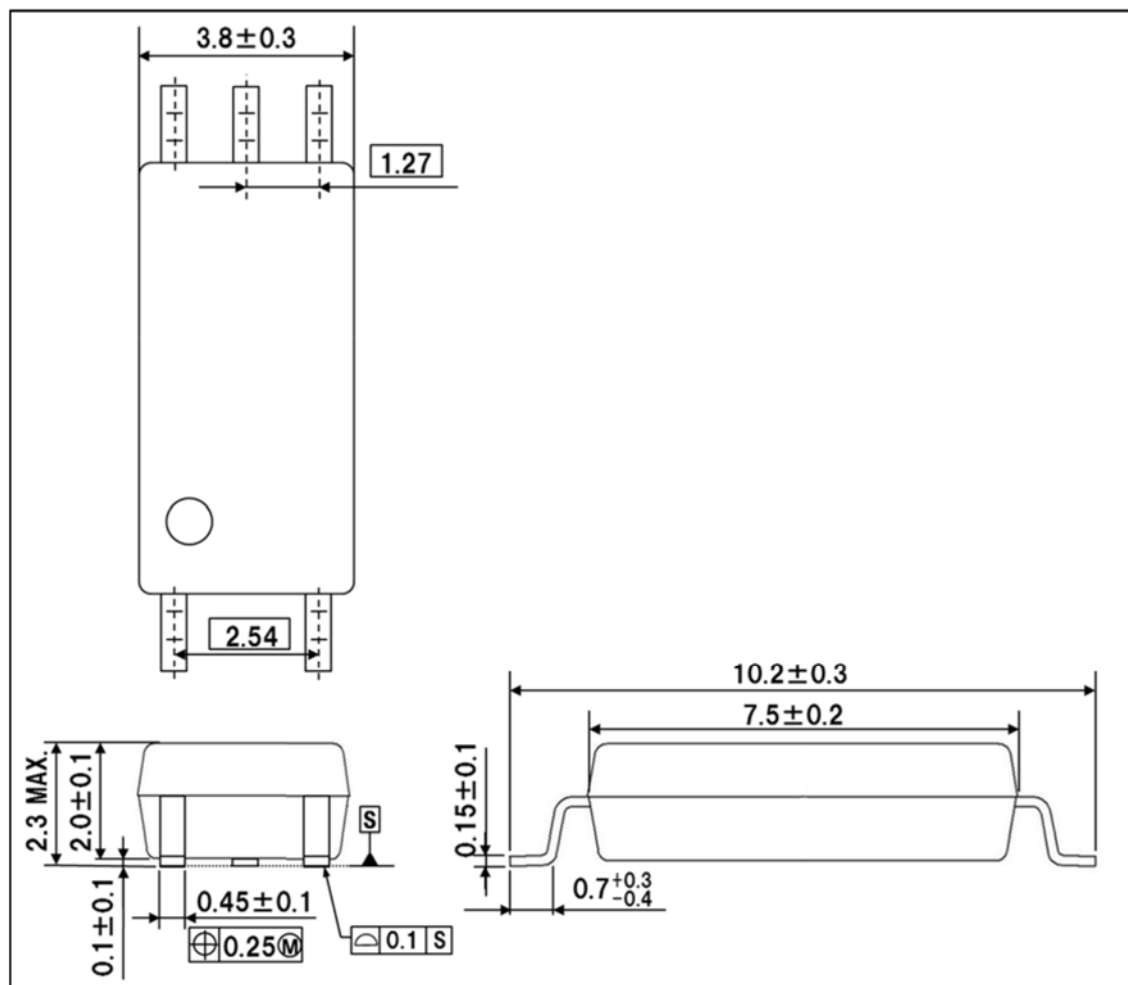


APPLICATIONS

- IPM Driver
- General purpose inverter

Start of mass production
Mar.2016

PACKAGE DIMENSIONS (UNIT: mm)

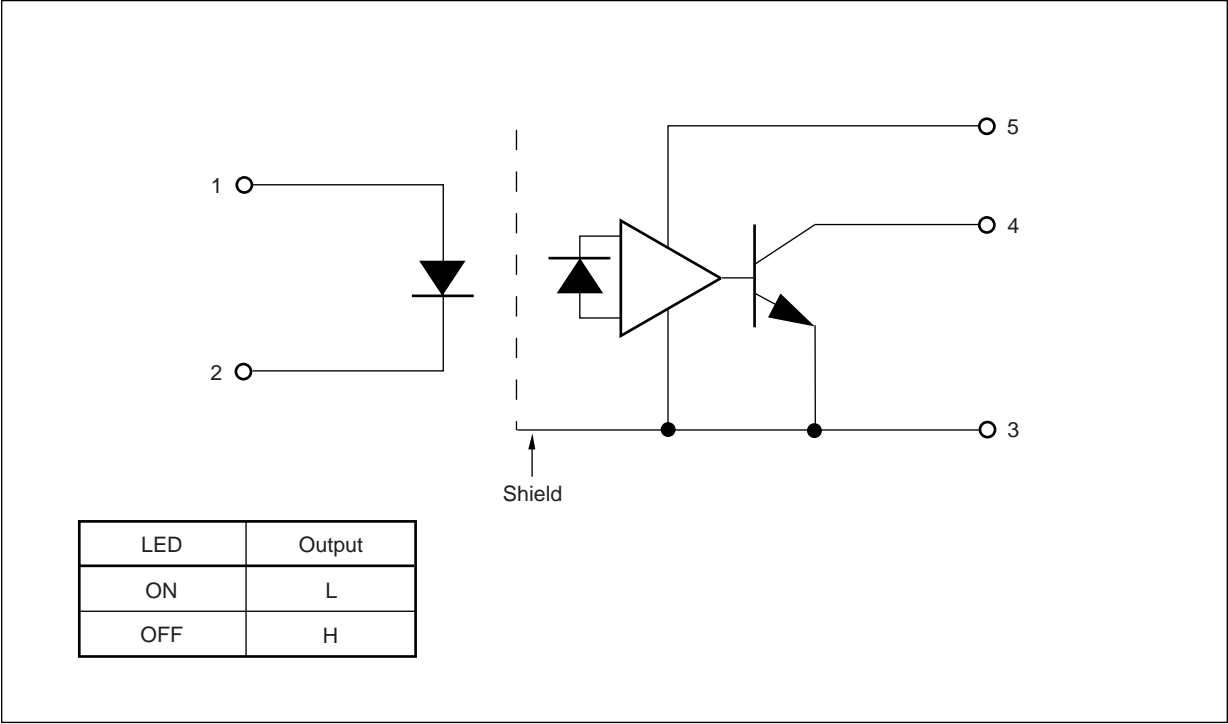


Weight : 0.119g (typ.)

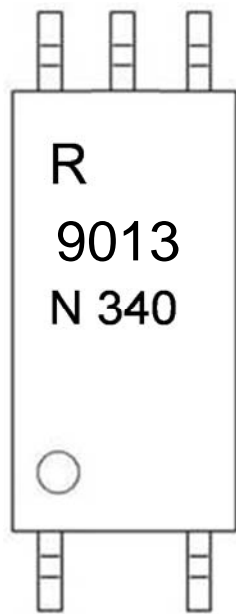
PHOTOCOUPLER CONSTRUCTION

Parameter	MIN.
Air Distance	8 mm
Outer Creepage Distance	8 mm
Isolation Distance	0.15 mm

BLOCK DIAGRAM



MARKING EXAMPLE



R		An initial of "Renesas"	
9013		Product Part Number	
○		No.1 pin Mark, Anode Mark	
N340	N	Rank Code	
	340	Assembly Lot	
		3	Last one-digit of Assembly Year
		40	Weekly Serial Code

ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number ^{*1}
PS9013	PS9013-Y-AX	Pb-Free and Halogen Free (Ni/Pd/Au)	20 pcs (Tape 20 pcs cut)	Standard products (UL,CSA approved)	PS9013
PS9013-F3	PS9013-Y-F3-AX		Embossed Tape 3 000 pcs/reel		
PS9013-V	PS9013-Y-V-AX		20 pcs (Tape 20 pcs cut)	UL,CSA approved DIN EN 60747-5-5 (VDE 0884-5): 2011-11 approved (Option)	
PS9013-V-F3	PS9013-Y-V-F3-AX		Embossed Tape 3 000 pcs/reel		

Note: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current*1	I_F	25	mA
	Reverse Voltage	V_R	5	V
Detector	Supply Voltage	V_{CC}	-0.5 to +30	V
	Output Voltage	V_O	-0.5 to +30	V
	Output Current	I_O	15	mA
	Power Dissipation*2	P_C	250	mW
Isolation Voltage*3		BV	5 000	Vr.m.s.
Operating Ambient Temperature		T_A	-40 to +125	$^\circ\text{C}$
Storage Temperature		T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: *1. Reduced to 0.325 mA/ $^\circ\text{C}$ at $T_A = 85^\circ\text{C}$ or more.

*2. Reduced to 4.15 mW/ $^\circ\text{C}$ at $T_A = 85^\circ\text{C}$ or more

*3. AC voltage for 1 minute at $T_A = 25^\circ\text{C}$, RH = 60% between input and output.

Pins 1-3 shorted together, 4-6 shorted together.

RECOMMENDED OPERATING CONDITIONS

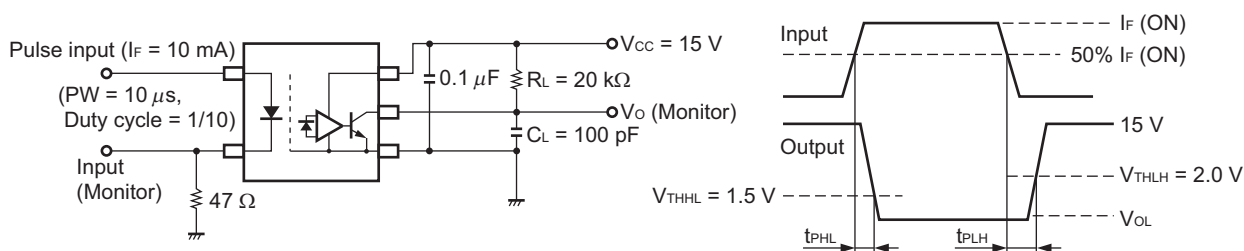
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	V_{CC}	4.5	15	25	V
Forward Current (ON)	I_F (ON)	8		12	mA
Forward Voltage (OFF)	V_F (OFF)	-2		0.8	V

ELECTRICAL CHARACTERISTICS ($T_A = -40$ to $+125^\circ\text{C}$, $V_{CC} = 15\text{ V}$, unless otherwise specified)

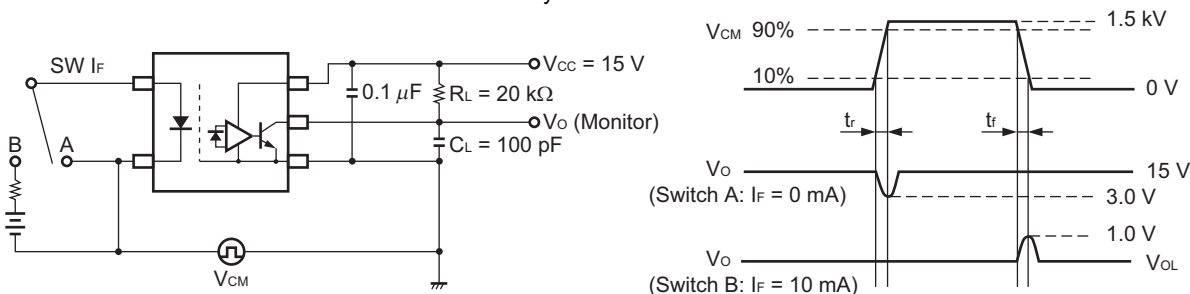
Parameter	Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	$I_F = 10\text{ mA}$	1.35	1.56	1.75	V
	Reverse Current	$V_R = 3\text{ V}$			10	μA
	Terminal Capacitance	$V = 0\text{ V}$, $f = 1\text{ MHz}$, $T_A = 25^\circ\text{C}$		30		pF
Detector	Low Level Output Voltage	$I_F = 10\text{ mA}$, $I_{OL} = 2.4\text{ mA}$		0.13	0.6	V
	High Level Output Current	$V_{CC} = V_O = 20\text{ V}$, $V_F = 0.8\text{ V}$		0.01	50	μA
	High Level Supply Current	$V_{CC} = 20\text{ V}$, $V_F = 0.8\text{ V}$, $V_O = \text{open}$		1.0	1.3	mA
	Low Level Supply Current	$V_{CC} = 20\text{ V}$, $I_F = 10\text{ mA}$, $V_O = \text{open}$		1.0	1.3	mA
Coupled	Threshold Input Current ($H \rightarrow L$)	$V_O = 0.8\text{ V}$, $I_O = 0.75\text{ mA}$		1.5	5.0	mA
	Isolation Resistance	$V_{I-O} = 1\text{ kV}_{DC}$, $R_H = 40$ to 60% , $T_A = 25^\circ\text{C}$	10^{11}			Ω
	Isolation Capacitance	$V = 0\text{ V}$, $f = 1\text{ MHz}$, $T_A = 25^\circ\text{C}$		0.7		pF
	Propagation Delay Time ($H \rightarrow L$)*2	$I_F = 10\text{ mA}$, $R_L = 20\text{ k}\Omega$, $C_L = 100\text{ pF}$, $V_{THHL} = 1.5\text{ V}$, $V_{THLH} = 2.0\text{ V}$		250	500	ns
	Propagation Delay Time ($L \rightarrow H$)*2			520	750	
	Maximum Propagation Delays		-200	270	650	
	Pulse Width Distortion (PWD)*2			270	650	
	Common Mode Transient Immunity at High Level Output*3	$T_A = 25^\circ\text{C}$, $I_F = 0\text{ mA}$, $V_O > 3.0\text{ V}$, $V_{CM} = 1.5\text{ kV}$, $R_L = 20\text{ k}\Omega$, $C_L = 100\text{ pF}$	50			$\text{kV}/\mu\text{s}$
	Common Mode Transient Immunity at Low Level Output*3	$T_A = 25^\circ\text{C}$, $I_F = 10\text{ mA}$, $V_O < 1.0\text{ V}$, $V_{CM} = 1.5\text{ kV}$, $R_L = 20\text{ k}\Omega$, $C_L = 100\text{ pF}$	50			$\text{kV}/\mu\text{s}$

Notes*: 1. Typical values at $T_A = 25^\circ\text{C}$.

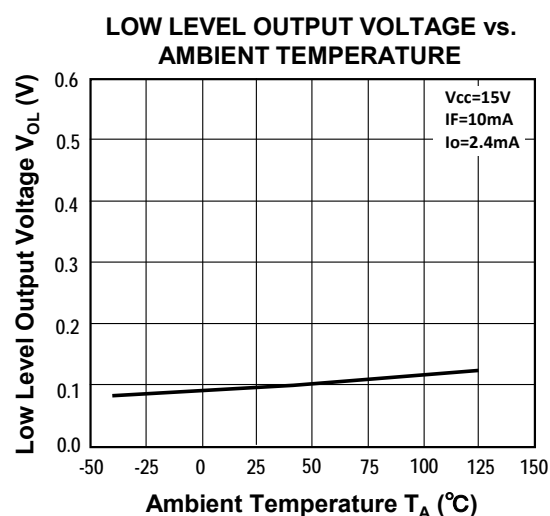
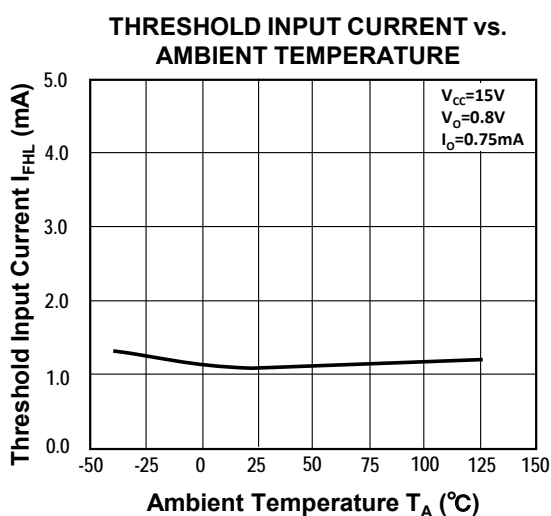
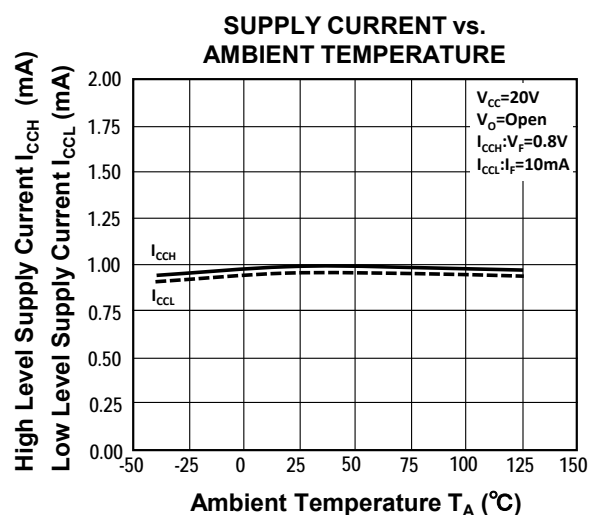
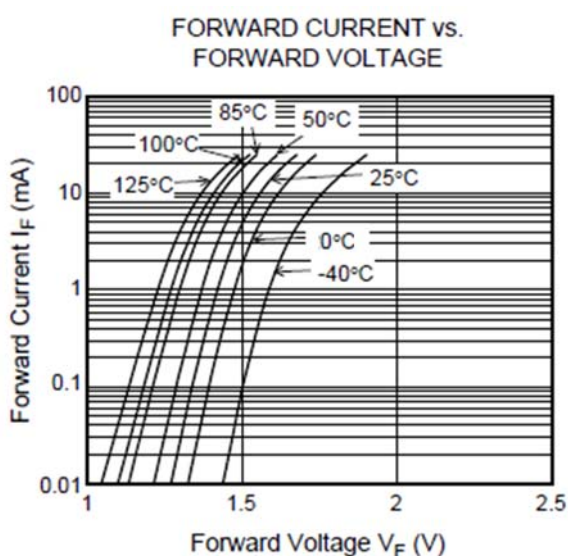
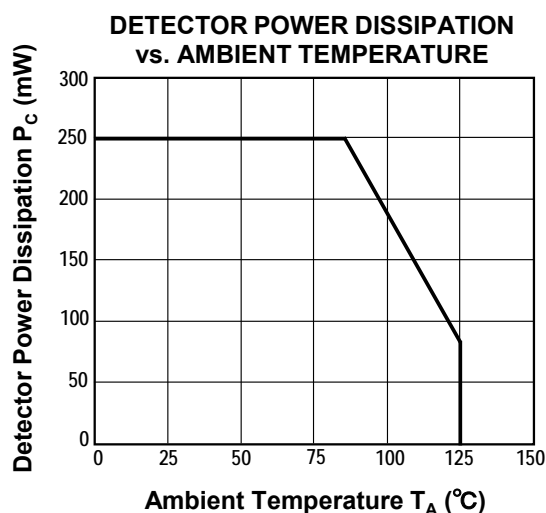
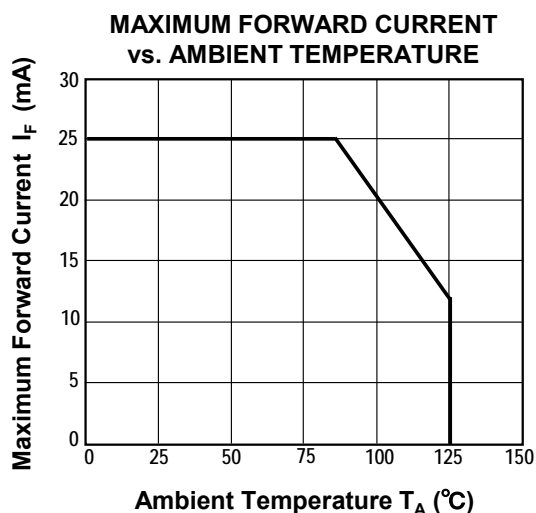
2. Test circuit for propagation delay time



3. Test circuit for common mode transient immunity

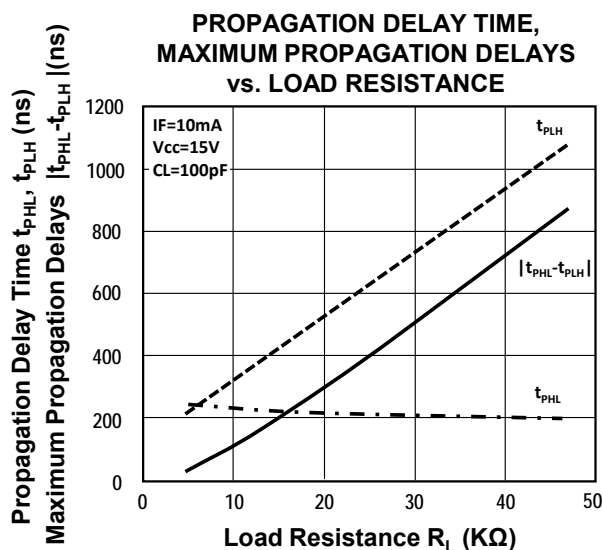
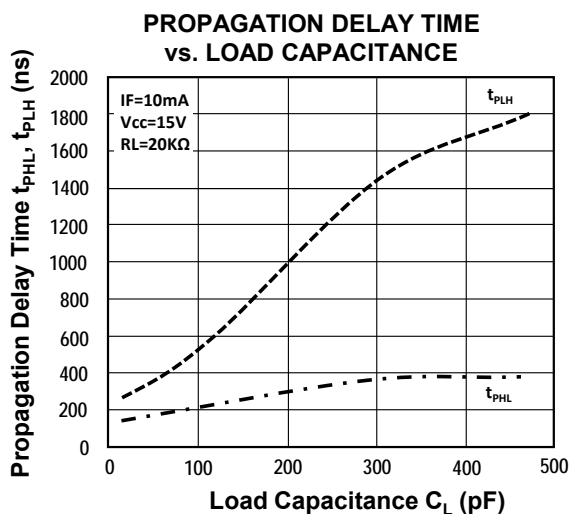
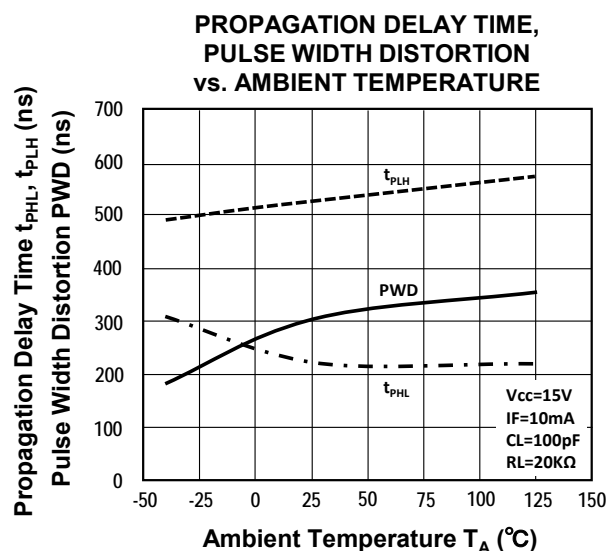
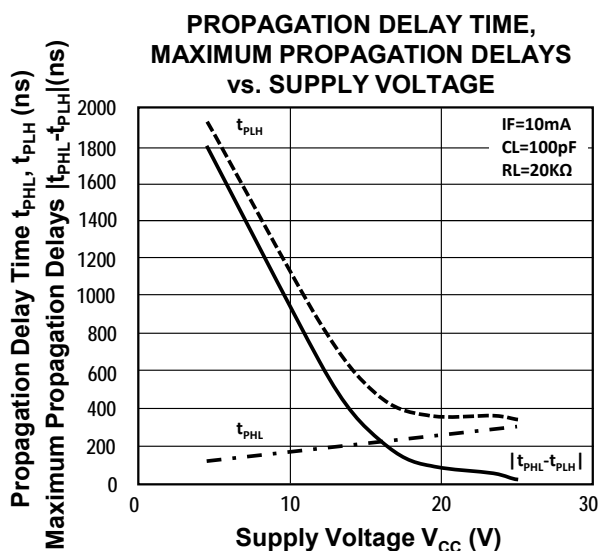
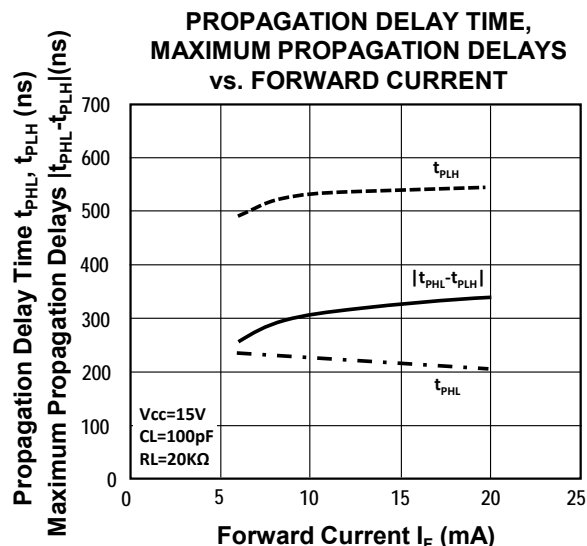
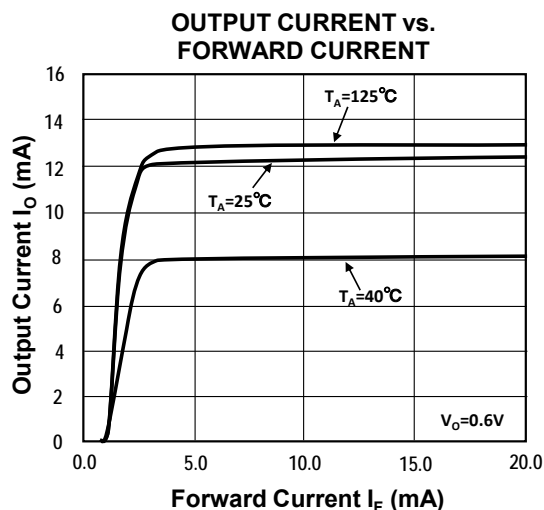


TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise specified)



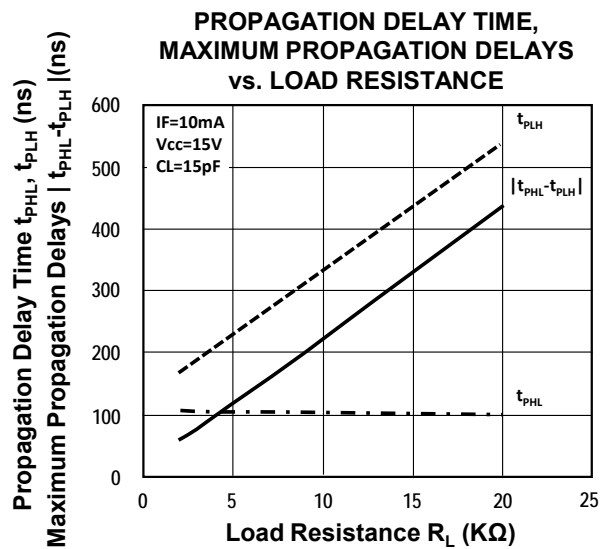
Remark The graphs indicate nominal characteristics.

TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)



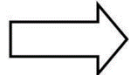
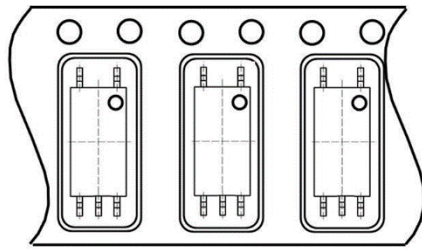
Remark The graphs indicate nominal characteristics.

TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)



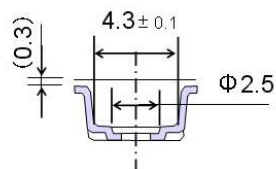
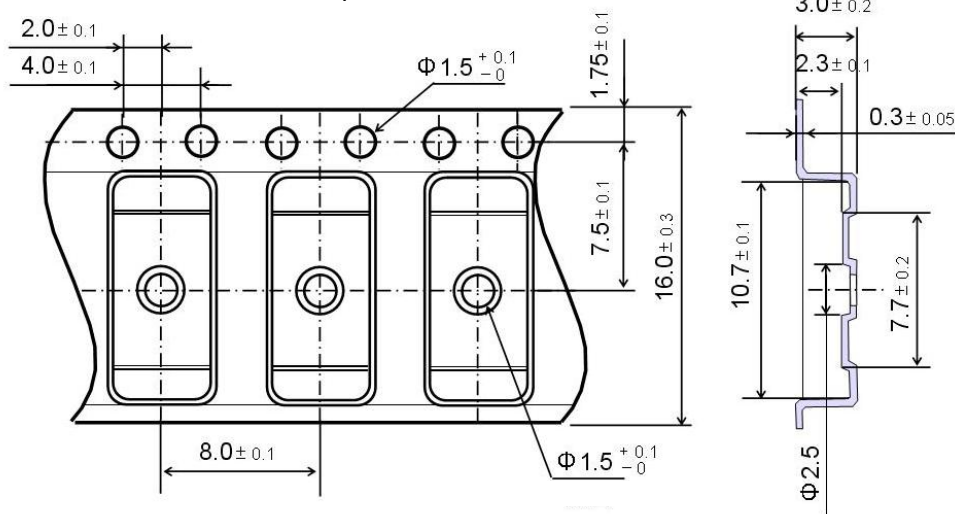
Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)

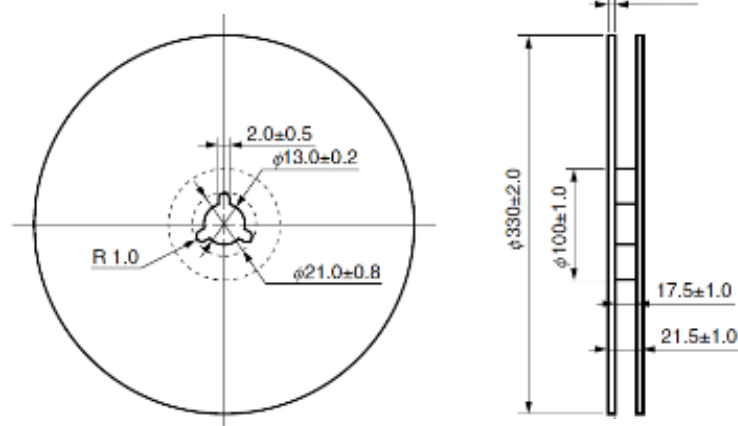


Tape Direction

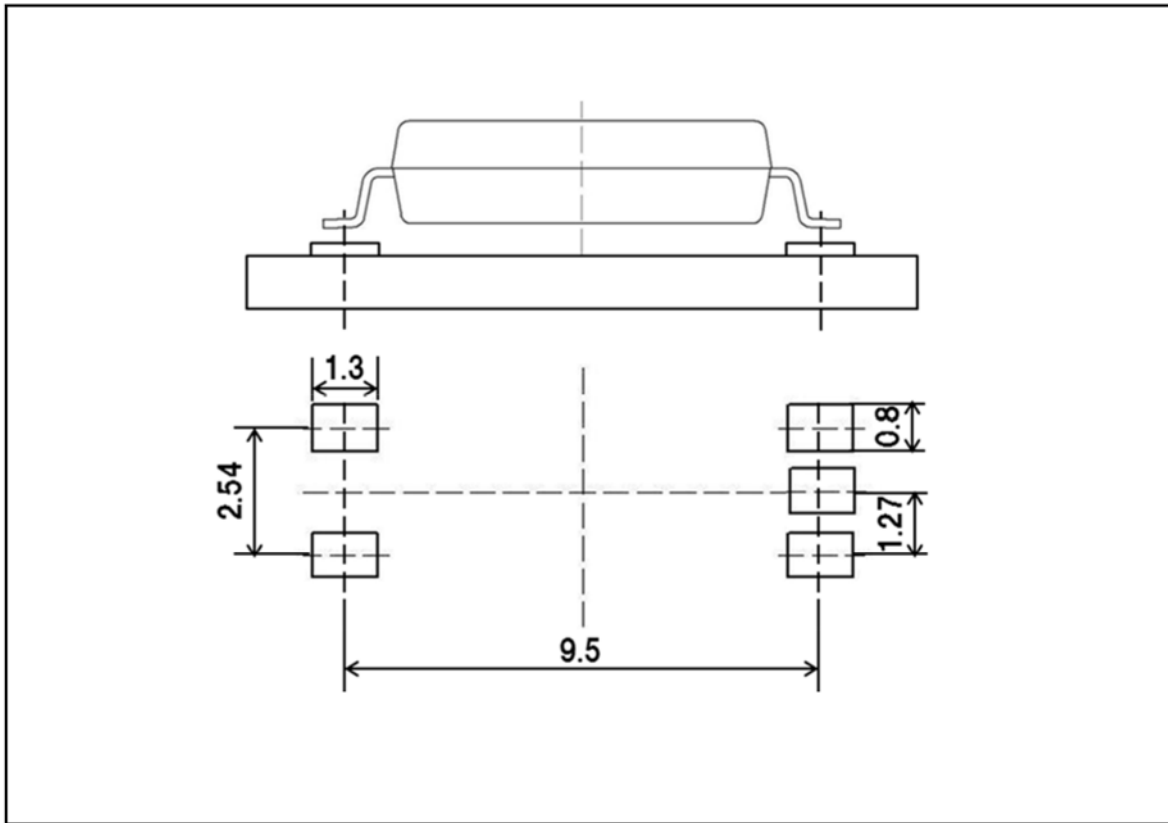
Outline and Dimensions (Taps)



Outline and Dimensions (Reel)



Packing: 3000 pcs/reel

RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)

Remark All dimensions in this figure must be evaluated before use.

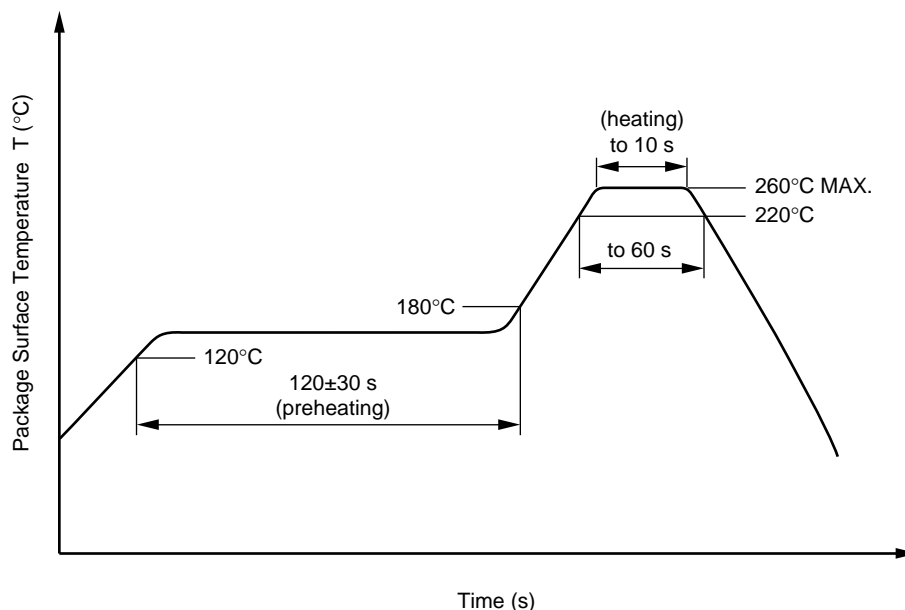
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

- Peak reflow temperature 260°C or below (package surface temperature)
- Time of peak reflow temperature 10 seconds or less
- Time of temperature higher than 220°C 60 seconds or less
- Time to preheat temperature from 120 to 180°C 120±30 s
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

- Peak Temperature (lead part temperature) 350°C or below
- Time (each pins) 3 seconds or less
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(4) Cautions

- Fluxes Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

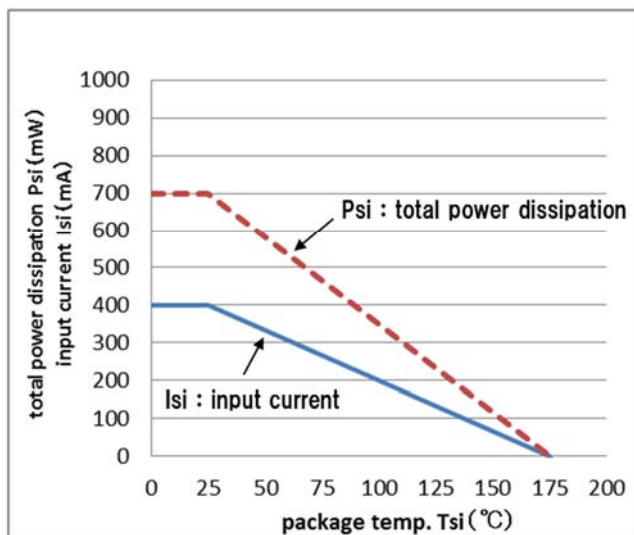
USAGE CAUTIONS

1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
2. By-pass capacitor of more than 0.1 μF is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
3. Avoid storage at a high temperature and high humidity.

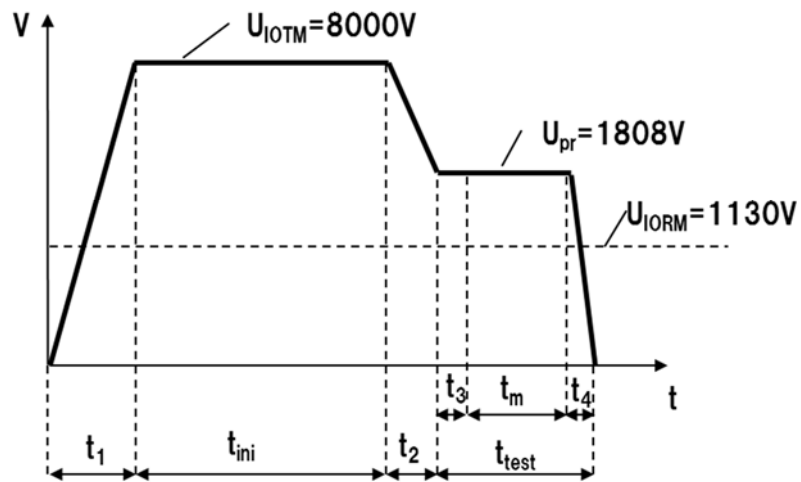
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/125/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.6 \times U_{IORM}$, $P_d < 5 \text{ pC}$	U_{IORM} U_{pr}	1 130 1 808	V_{peak} V_{peak}
Test voltage (partial discharge test, procedure b for all devices) $U_{pr} = 1.875 \times U_{IORM}$, $P_d < 5 \text{ pC}$	U_{pr}	2 119	V_{peak}
Highest permissible overvoltage	U_{IOTM}	8 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	400	
Material group (DIN EN 60664-1 VDE0110 Part 1)		II	
Storage temperature range	T_{stg}	-55 to +150	°C
Operating temperature range	T_A	-40 to +125	°C
Isolation resistance, minimum value $V_{IO} = 500 \text{ V dc at } T_A = 25^\circ\text{C}$ $V_{IO} = 500 \text{ V dc at } T_A \text{ MAX. at least } 100^\circ\text{C}$	Ris MIN. Ris MIN.	10^{12} 10^{11}	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I_F , $Psi = 0$) Power (output or total power dissipation) Isolation resistance $V_{IO} = 500 \text{ V dc at } T_A = T_{Si}$	T_{Si} I_{Si} P_{Si} Ris MIN.	175 400 700 10^9	°C mA mW Ω

Dependence of maximum safety ratings with package temperature



Method A Destructive Test, Type and Sample test



$t_1, t_2 = 1 \text{ to } 10 \text{ sec}$

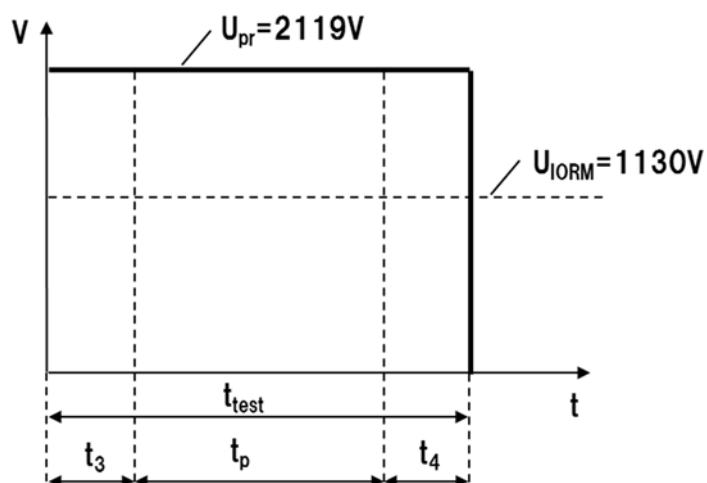
$t_3, t_4 = 1 \text{ sec}$

$t_m \text{ (PARTIAL DISCHARGE)} = 10 \text{ sec}$

$t_{test} = 12 \text{ sec}$

$t_{ini} = 60 \text{ sec}$

Method b Non-destructive Test, 100% Production Test



$t_3, t_4 = 0.1 \text{ sec}$

$t_p \text{ (PARTIAL DISCHARGE)} = 1.0 \text{ sec}$

$t_{test} = 1.2 \text{ sec}$

Caution	<p>GaAs Products</p>	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none">• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.<ol style="list-style-type: none">1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.• Do not burn, destroy, cut, crush, or chemically dissolve the product.• Do not lick the product or in any way allow it to enter the mouth.
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